

L Number	Hits	Search Text	DB	Time stamp
1	0	(T near RAM) and (buried near vertical near thyristor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 14:51
8	312	(T near RAM) and (buried \$4 vertical \$4 thyristor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 14:53
9	311	(T near RAM) and (buried \$4 vertical \$4 thyristor)and (horizontal \$4 transfer \$4 gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 14:55
10	311	(T near RAM) and (buried \$4 vertical \$4 thyristor)and (horizontal \$4 pseudo \$4 transfer \$4 gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 14:56
12	9	(T near RAM) and (buried \$4 vertical \$4 thyristor)and (horizontal \$4 pseudo \$4 stacked \$4 transfer \$4 gate)and (cell near size)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 14:58
11	311	(T near RAM) and (buried \$4 vertical \$4 thyristor)and (horizontal \$4 pseudo \$4 stacked \$4 transfer \$4 gate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 15:02

L Number	Hits	Search Text	DB	Time stamp
1	108	(T near RAM) and cell	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 15:40
8	14709	SOI	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 15:41
15	11	((T near RAM) and cell) and SOI	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 15:42
22	3586	THyristor and vertic\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 15:43
29	848	THyristor and vertic\$3 and bur\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 15:43
36	4	((T near RAM) and cell) and (THyristor and vertic\$3 and bur\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/09 15:43